
	<h2 style="color: red;">SUD50N02-04P-E3</h2>
	<p>Hersteller-Teilenummer: SUD50N02-04P-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 50A DPAK</p> <p>Datenblätter:  SUD50N02-04P-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4000 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD50N02-04P-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 20V 50A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4000 pcs Stock
detaillierte Beschreibung	N-Channel 20V 50A (Tc) 8.3W (Ta), 136W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	8.3W (Ta), 136W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	50A (Tc)
Rds On (Max) @ Id, Vgs	4.3 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	60nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	5000pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD50N02-04P-E3TR

SUD50N02-04P-E3 ist neu im Original, Suche SUD50N02-04P-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N02-04P-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50N02-04P-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 SUD50N02-06 VISHAY SUD50N02-06 VISHAY	 SUD50N02-04P-E3 Vishay / Siliconix MOSFET N-CH 20V 50A DPAK	 SUD50N02-06P-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 50A TO252	 SUD50N014-09P VISHAY SUD50N014-09P VISHAY
 SUD50N02-06P TO-252 SUD50N02-06P TO-252	 SUD50N02-04P VISHAY VISHAY TO-252	 SUD50N02-06-E3 VISHAY VISHAY TO-252	 SUD50N02-06P-E3 Vishay / Siliconix MOSFET N-CH 20V 50A TO252

heiße Teile

Mehr

⊛ SUD40N10-25-E3	↔ SUD40N10-25-E3	⇒ SUD40P03-20	D SUD42N03-3M9P	⇒ SUD42N03-3M9P-GE3
⊣ SUD42N03-3M9P-GE3	⊛ SUD45N03-09	D SUD45N05-20	⇒ SUD45N05-20L	⇒ SUD45N05-20L-E3
⊛ SUD45P03-09	⊣ SUD45P03-09-E3	⊛ SUD45P03-09-GE3	↔ SUD45P03-09-GE3	⇒ SUD45P03-10
D SUD45P03-10-E3	⊛ SUD45P03-10-E3	⊣ SUD45P03-15	⊛ SUD45P03-15-E3	⇒ SUD45P03-15-E3
⇒ SUD45P03-15-T1-E3	↔ SUD45P04-16P	⊛ SUD45P04-16P-T1-E3	⊣ SUD50N014-06P	⇒ SUD50N014-09P
↔ SUD50N02-04P-E3	⇒ SUD50N02-06	D SUD50N02-06P	⊛ SUD50N02-06P-E3	⊣ SUD50N02-06P-E3
⊛ SUD50N02-09P	D SUD50N02-09P-E3	⇒ SUD50N02-09P-E3	↔ SUD50N024-06P	⇒ SUD50N024-06P-T4
⊣ SUD50N024-06P-T4-E	⊛ SUD50N024-06P-T4E3	↔ SUD50N024-09	⇒ SUD50N024-09P	⇒ SUD50N024-09P-E4E3
⊛ SUD50N024-09P-T4	⊣ SUD50N024-09P-T4E3	⊛ SUD50N025	D SUD50N025-05P	⇒ SUD50N025-06P
↔ SUD50N025-06P-E3	⊛ SUD50N025-06P-E3	⊣ SUD50N025-09	⊛ SUD50N025-09BP-4E3	⇒ SUD50N025-09BP-E3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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